NPN Planar Silicon Darlington Transistor

[2SC3986]

5.6

Package Dimensions

324

18 1

unit:mm

2041A



2SC3986

Driver Applications

1: Base

2 : Collector 3 : Emitter

SANYO : TO-220ML

Applications

· Suitable for use in switching of L load (motor drivers, printer hammer drivers, relay drivers).

Features

- · High DC current gain.
- · Large current capacity and wide ASO.
- · On-chip Zener diode of 60±10V between collector and base.
- · Uniformity in collector-to-base breakdown voltage due to the adoption of an accurate impurity diffusion process.
- · High inductive load handling capability.
- · Micaless package facilitating mounting.

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter Symbol Conditions Ratings Unit Collector-to-Base Voltage 50* VCBO V Collector-to-Emitter Voltage V VCEO 50 V Emitter-to-Base Voltage 6 VEBO Collector Current 2 А I_{C} Collector Current (Pulse) 4 А ICP Base Current 0.4 А ΙB Collector Dissipation 2.0 W PC Tc=25°C 15 W Тj 150 °C Junction Temperature -55 to +150 °C Storage Temperature Tstg

* : With Zener diode (60±10V)

Electrical Characteristics at Ta = 25°C

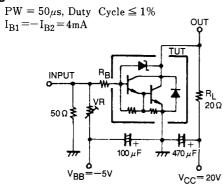
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} =40V, I _E =0			10	μA
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0			2	mA
DC Current Gain	hFE	V _{CE} =5V, I _C =1A	1000	4000		
Gain-Bandwidth Product	fT	V _{CE} =5V, I _C =1A		180		MHz
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =1A, I _B =4mA		1.0	1.5	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =1A, I _B =4mA			2.0	V

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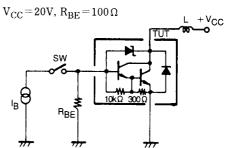
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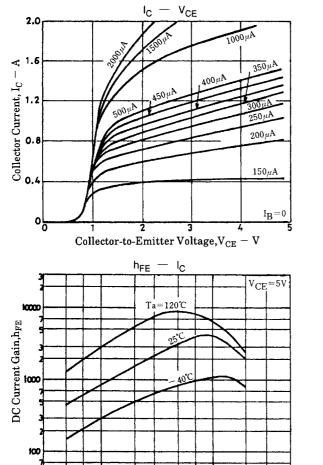
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =0.1mA, I _E =0	50	60	70	V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =1mA, R _{BE} =∞	50	60	70	V
Inductive Load Handling Capability	Es/b	L=100mH, R _{BE} =100Ω	25			mJ
Turn-ON Time	ton	See specified Test Circuit. V _{CC} =20V, I _C =1A, I _{B1} =-I _{B2} =4mA		0.2		μs
Storage Time	^t stg	See specified Test Circuit. V _{CC} =20V, I _C =1A, I _{B1} =-I _{B2} =4mA		3.5		μs
Fall Time	t _f	See specified Test Circuit. V _{CC} =20V, I _C =1A, I _{B1} =-I _{B2} =4mA		0.5		μs

Switching Time Test Circuit



Es/b Test Circuit

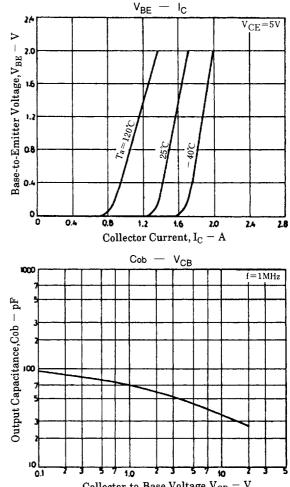




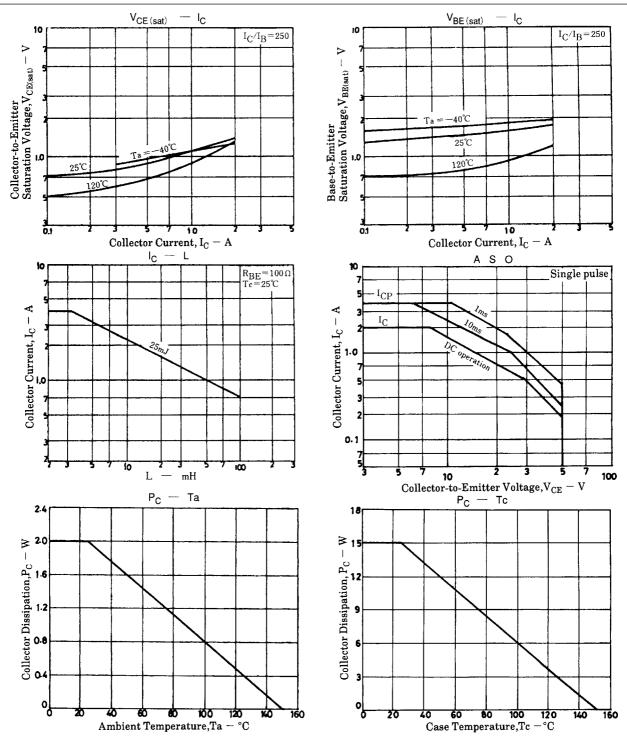
1.0

Collector Current, I_C - A

0.1



Collector-to-Base Voltage, $V_{CB} - V$



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